Low-ohmic single-pole double-throw analog switch

Rev. 1 — 23 May 2013

**Product data sheet** 

## 1. General description

The NX3L1G3157-Q100 is a low-ohmic single-pole double-throw analog switch suitable for use as an analog or digital 2:1 multiplexer/demultiplexer. It has a digital select input (S), two independent inputs/outputs (Y0 and Y1) and a common input/output (Z). Schmitt trigger action at the digital input makes the circuit tolerant to slower input rise and fall times.

The NX3L1G3157-Q100 allows signals with amplitude up to V<sub>CC</sub> to be transmitted from Z to Y0 or Y1; or from Y0 or Y1 to Z. Its low ON resistance (0.5  $\Omega$ ) and flatness (0.13  $\Omega$ ) ensures minimal attenuation and distortion of transmitted signals.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

## 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
   Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance:
  - 1.6  $\Omega$  (typical) at V<sub>CC</sub> = 1.4 V
  - 1.0 Ω (typical) at V<sub>CC</sub> = 1.65 V
  - 0.55  $\Omega$  (typical) at V<sub>CC</sub> = 2.3 V
  - 0.50  $\Omega$  (typical) at V<sub>CC</sub> = 2.7 V
  - 0.50  $\Omega$  (typical) at V<sub>CC</sub> = 4.3 V
- Break-before-make switching
- High noise immunity
- ESD protection:
  - MIL-STD-883, method 3015 Class 3A exceeds 7500 V
  - HBM JESD22-A114F Class 3A exceeds 7500 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
  - CDM AEC-Q100-011 revision B exceeds 1000 V
  - IEC61000-4-2 contact discharge exceeds 8000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD78 Class II Level A
- Direct interface with TTL levels at 3.0 V
- Control input accepts voltages above supply voltage
- High current handling capability (350 mA continuous current under 3.3 V supply)



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## 3. Applications

- Cell phone
- PDA
- Portable media player

## 4. Ordering information

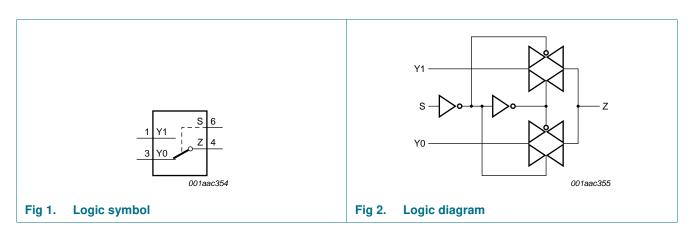
Table 1. Ordering information											
Type number Package											
	Temperature range	Name	Description	Version							
NX3L1G3157GW-Q100	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363							

## 5. Marking

Table 2.         Marking codes <sup>[1]</sup>	
Type number	Marking code
NX3L1G3157GW-Q100	MJ

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

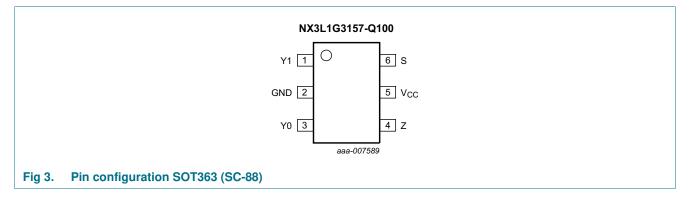
## 6. Functional diagram



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## 7. Pinning information

## 7.1 Pinning



## 7.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
Y1	1	independent input or output
GND	2	ground (0 V)
Y0	3	independent input or output
Z	4	common output or input
V <sub>CC</sub>	5	supply voltage
S	6	select input

## 8. Functional description

#### Table 4.Function table<sup>[1]</sup>

Input S	Channel on
L	YO
Н	Y1

[1] H = HIGH voltage level; L = LOW voltage level.

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## 9. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
VI	input voltage	select input S	<u>[1]</u> –0.5	+4.6	V
V <sub>SW</sub>	switch voltage		<u>[2]</u> –0.5	$V_{CC} + 0.5$	V
I <sub>IK</sub>	input clamping current	$V_{l} < -0.5 V$	-50	-	mA
I <sub>SK</sub>	switch clamping current	$V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{\rm CC}$ + 0.5 V	-	±50	mA
I <sub>SW</sub>	switch current	$V_{SW}$ > -0.5 V or $V_{SW}$ < $V_{CC}$ + 0.5 V; source or sink current	-	±350	mA
		V <sub>SW</sub> > -0.5 V or V <sub>SW</sub> < V <sub>CC</sub> + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	<u>[3]</u> _	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For SC-88 package: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K.

## **10. Recommended operating conditions**

#### Table 6. Recommended operating conditions

	1 5				
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		1.4	4.3	V
VI	input voltage	select input S	0	4.3	V
V <sub>SW</sub>	switch voltage		<u>[1]</u> 0	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$	[2] _	200	ns/V

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current flows from terminal Yn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

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## **11. Static characteristics**

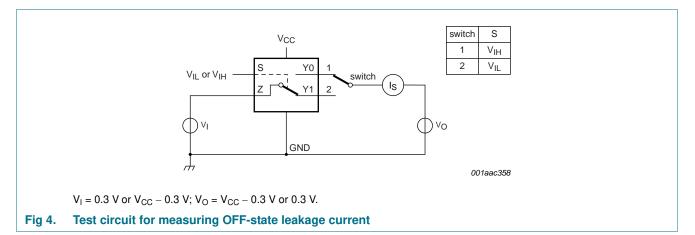
### Table 7. Static characteristics

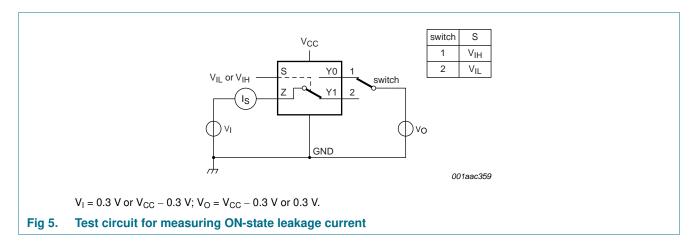
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	ameter Conditions	Tar	T <sub>amb</sub> = 25 °C			T <sub>amb</sub> = -40 °C to +125 °C		
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 1.4 V to 1.95 V	$0.65V_{CC}$	-	-	$0.65V_{CC}$	-	-	V
	input voltage	$V_{CC} = 2.3 \text{ V}$ to 2.7 V	1.7	-	-	1.7	-	-	V
		$V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	2.0	-	-	V
		$V_{CC} = 3.6 \text{ V} \text{ to } 4.3 \text{ V}$	$0.7V_{CC}$	-	-	$0.7V_{CC}$	-	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 1.4 V to 1.95 V	-	-	$0.35V_{CC}$	-	$0.35V_{CC}$	$0.35V_{CC}$	V
	input voltage	$V_{CC} = 2.3 \text{ V}$ to 2.7 V	-	-	0.7	-	0.7	0.7	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.8	-	0.8	0.8	V
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	-	$0.3V_{CC}$	-	$0.3V_{CC}$	$0.3V_{CC}$	V
I	input leakage current	select input S; V <sub>I</sub> = GND to 4.3 V; V <sub>CC</sub> = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μΑ
I <sub>S(OFF)</sub>	OFF-state leakage	Y0 and Y1 port; see <u>Figure 4</u>							
	current	$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	-	±5	-	±50	±500	nA
		$V_{CC} = 3.6 V \text{ to } 4.3 V$	-	-	±10	-	±50	±500	nA
I <sub>S(ON)</sub>	ON-state	Z port; see Figure 5							
	leakage current	$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	-	±5	-	±50	±500	nA
	current	$V_{CC} = 3.6 V \text{ to } 4.3 V$	-	-	±10	-	±50	±500	nA
I <sub>CC</sub>	supply current	$V_{I} = V_{CC}$ or GND; $V_{SW} = GND$ or $V_{CC}$							
		$V_{CC} = 3.6 V$	-	-	100	-	690	6000	nA
		$V_{CC} = 4.3 V$	-	-	150	-	800	7000	nA
Cı	input capacitance		-	1.0	-	-	-	-	рF
$C_{S(OFF)}$	OFF-state capacitance		-	35	-	-	-	-	pF
C <sub>S(ON)</sub>	ON-state capacitance		-	130	-	-	-	-	pF

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### 11.1 Test circuits





### Low-ohmic single-pole double-throw analog switch

### 11.2 ON resistance

#### Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 7 to Figure 13.

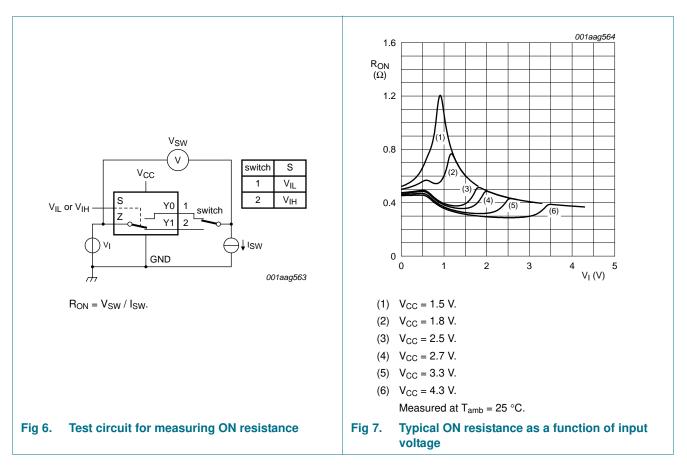
Symbol	Parameter	Conditions	T <sub>amb</sub> = -	-40 °C to	+85 °C	$T_{amb} = -40$ °	C to +125 °C	Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Max	
R <sub>ON(peak)</sub>	ON resistance (peak)	$V_I = GND$ to $V_{CC}$ ; $I_{SW} = 100 \text{ mA}$ ; see <u>Figure 6</u>						
		$V_{CC} = 1.4 V$	-	1.6	3.7	-	4.1	Ω
		V <sub>CC</sub> = 1.65 V	-	1.0	1.6	-	1.7	Ω
		$V_{CC} = 2.3 V$	-	0.55	0.8	-	0.9	Ω
		$V_{CC} = 2.7 V$	-	0.5	0.75	-	0.9	Ω
		$V_{CC} = 4.3 V$	-	0.5	0.75	-	0.9	Ω
$\Delta R_{ON}$	ON resistance mismatch between channels	$V_{I} = GND \text{ to } V_{CC};$ [2] $I_{SW} = 100 \text{ mA}$						
		$V_{CC} = 1.4 V$	-	0.04	0.3	-	0.3	Ω
		$V_{CC} = 1.65 V$	-	0.04	0.2	-	0.3	Ω
		$V_{CC} = 2.3 V$	-	0.02	0.08	-	0.1	Ω
		$V_{CC} = 2.7 V$	-	0.02	0.075	-	0.1	Ω
		$V_{CC} = 4.3 V$	-	0.02	0.075	-	0.1	Ω
$R_{ON(flat)}$	ON resistance (flatness)							
		$V_{CC} = 1.4 V$	-	1.0	3.3	-	3.6	Ω
		V <sub>CC</sub> = 1.65 V	-	0.5	1.2	-	1.3	Ω
		$V_{CC} = 2.3 V$	-	0.15	0.3	-	0.35	Ω
		$V_{CC} = 2.7 V$	-	0.13	0.3	-	0.35	Ω
		$V_{CC} = 4.3 V$	-	0.2	0.4	-	0.45	Ω

[1] Typical values are measured at  $T_{amb} = 25 \text{ °C}$ .

[2] Measured at identical V<sub>CC</sub>, temperature and input voltage.

[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V<sub>CC</sub> and temperature.

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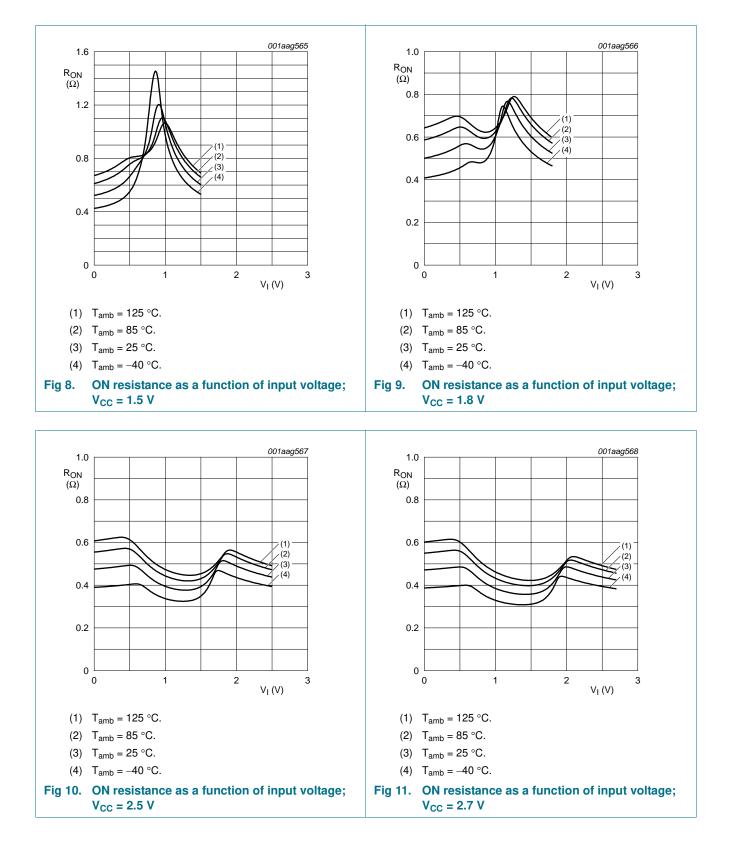


## 11.3 ON resistance test circuit and graphs

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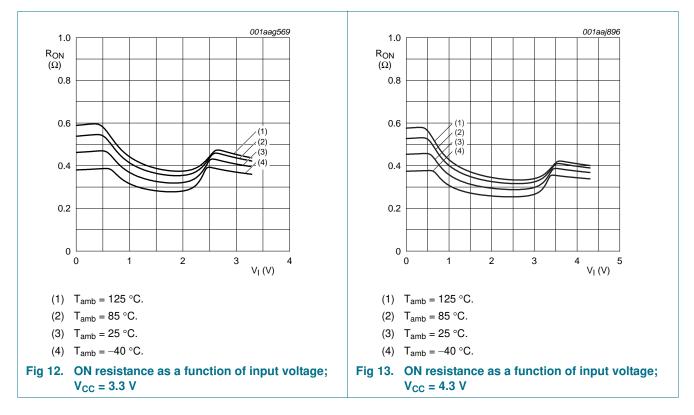


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### Low-ohmic single-pole double-throw analog switch



## 12. Dynamic characteristics

#### Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 16.

Symbol	Parameter	Conditions	Ta	<sub>mb</sub> = 25	°C	T <sub>amb</sub> =	–40 °C to	+125 °C	Unit
		1	Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	
t <sub>en</sub>	enable time	S to Z or Yn; see <u>Figure 14</u>							
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	-	28	43	-	48	52	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	23	35	-	38	42	ns
		$V_{CC}$ = 2.3 V to 2.7 V	-	17	27	-	29	32	ns
		$V_{CC}$ = 2.7 V to 3.6 V	-	14	25	-	27	30	ns
		$V_{CC}$ = 3.6 V to 4.3 V	-	14	25	-	27	30	ns
t <sub>dis</sub>	disable time	S to Z or Yn; see <u>Figure 14</u>							
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	-	9	20	-	25	30	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	6	15	-	20	23	ns
		$V_{CC}$ = 2.3 V to 2.7 V	-	5	11	-	14	16	ns
		$V_{CC}$ = 2.7 V to 3.6 V	-	4	10	-	12	14	ns
		$V_{CC}$ = 3.6 V to 4.3 V	-	4	10	-	12	14	ns

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Symbol	Parameter	Conditions		T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = -40 °C to +125 °C			Unit	
				Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	-
t <sub>b-m</sub> break-before-make time	see Figure 15	[2]								
	time	V <sub>CC</sub> = 1.4 V to 1.6 V		-	19	-	4	-	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		-	17	-	4	-	-	ns
		$V_{CC}$ = 2.3 V to 2.7 V		-	13	-	2	-	-	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		-	10	-	2	-	-	ns
		$V_{CC} = 3.6 \text{ V} \text{ to } 4.3 \text{ V}$		-	10	-	2	-	-	ns

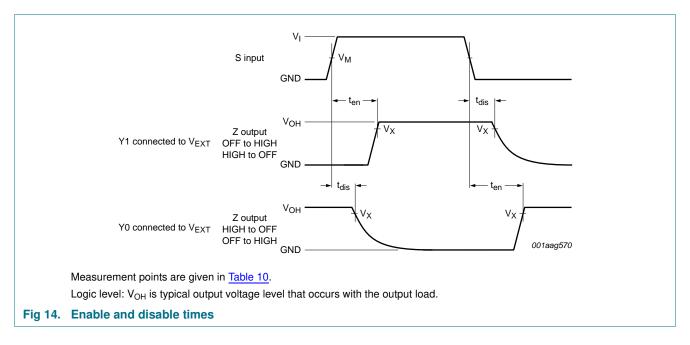
#### Table 9. Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 16.

[1] Typical values are measured at  $T_{amb}$  = 25 °C and  $V_{CC}$  = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

[2] Break-before-make guaranteed by design.

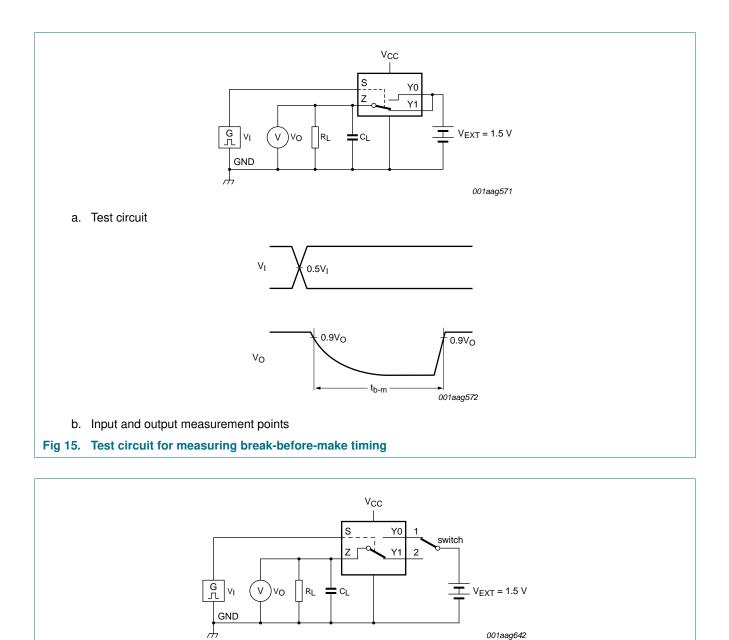
### 12.1 Waveform and test circuits



#### Table 10. Measurement points

Supply voltage	Input	Output
V <sub>CC</sub>	V <sub>M</sub>	Vx
1.4 V to 4.3 V	0.5V <sub>CC</sub>	0.9V <sub>OH</sub>

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Test data is given in <u>Table 11</u>. Definitions test circuit:

 $R_L$  = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $V_{EXT}$  = External voltage for measuring switching times.

### Fig 16. Load circuit for switching times

#### Table 11. Test data

Supply voltage	Input		Load	
V <sub>cc</sub>	V <sub>I</sub> t <sub>r</sub> , t <sub>f</sub>		CL	RL
1.4 V to 4.3 V	V <sub>CC</sub>	$\leq$ 2.5 ns	35 pF	50 Ω

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## 12.2 Additional dynamic characteristics

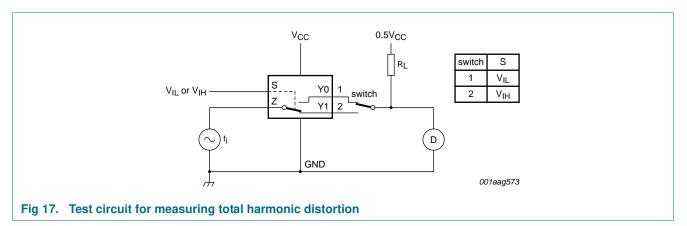
#### Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_1 = GND$  or  $V_{CC}$  (unless otherwise specified);  $t_r = t_f \le 2.5 \text{ ns}$ ;  $T_{amb} = 25 \text{ °C}$ .

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	total harmonic distortion	$f_i$ = 20 Hz to 20 kHz; $R_L$ = 32 $\Omega$ ; see <u>Figure 17</u>	<u>[1]</u>			
		$V_{CC} = 1.4 \text{ V}; \text{ V}_{I} = 1 \text{ V} (p-p)$	-	0.15	-	%
		V <sub>CC</sub> = 1.65 V; V <sub>I</sub> = 1.2 V (p-p)	-	0.10	-	%
		V <sub>CC</sub> = 2.3 V; V <sub>I</sub> = 1.5 V (p-p)	-	0.02	-	%
		V <sub>CC</sub> = 2.7 V; V <sub>I</sub> = 2 V (p-p)	-	0.02	-	%
		V <sub>CC</sub> = 4.3 V; V <sub>I</sub> = 2 V (p-p)	-	0.02	-	%
f <sub>(-3dB)</sub>	-3 dB frequency	$R_L = 50 \Omega$ ; see <u>Figure 18</u>	<u>[1]</u>			
	response	V <sub>CC</sub> = 1.4 V to 4.3 V	-	60	-	MHz
$\alpha_{\text{iso}}$	isolation (OFF-state)	$f_i = 100 \text{ kHz}; \text{ R}_L = 50 \Omega; \text{ see } \frac{\text{Figure 19}}{100 \text{ kHz}}$	<u>[1]</u>			
		$V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$	-	-90	-	dB
V <sub>ct</sub>	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$ ; $C_L = 50 \text{ pF}$ ; $R_L = 50 \Omega$ ; see Figure 20				
		V <sub>CC</sub> = 1.4 V to 3.6 V	-	0.2	-	V
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	0.3	-	V
Q <sub>inj</sub>	charge injection	$      f_i = 1 \text{ MHz}; C_L = 0.1 \text{ nF}; R_L = 1 \text{ M}\Omega; V_{gen} = 0 \text{ V}; \\ R_{gen} = 0 \Omega; \text{ see } \frac{\text{Figure 21}}{2}      $				
		$V_{CC} = 1.5 V$	-	3	-	рС
		$V_{CC} = 1.8 V$	-	4	-	рС
		$V_{CC} = 2.5 V$	-	6	-	рС
		$V_{CC} = 3.3 V$	-	9	-	рС
		$V_{CC} = 4.3 V$	-	15	-	рС

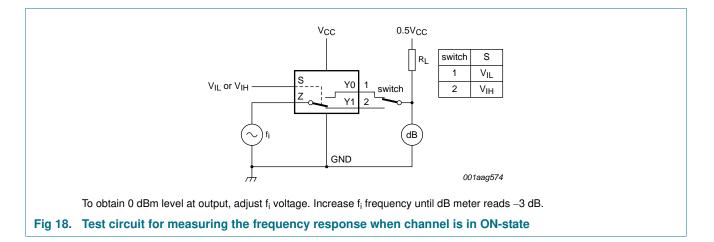
[1]  $f_i$  is biased at 0.5V<sub>CC</sub>.

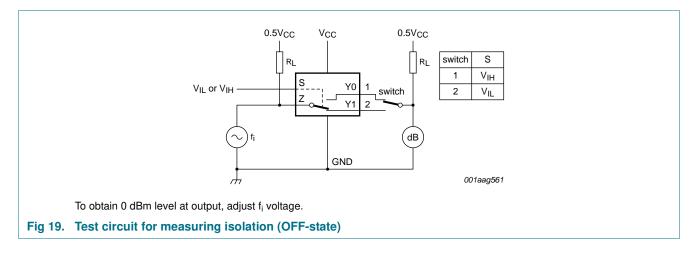
## 12.3 Test circuits



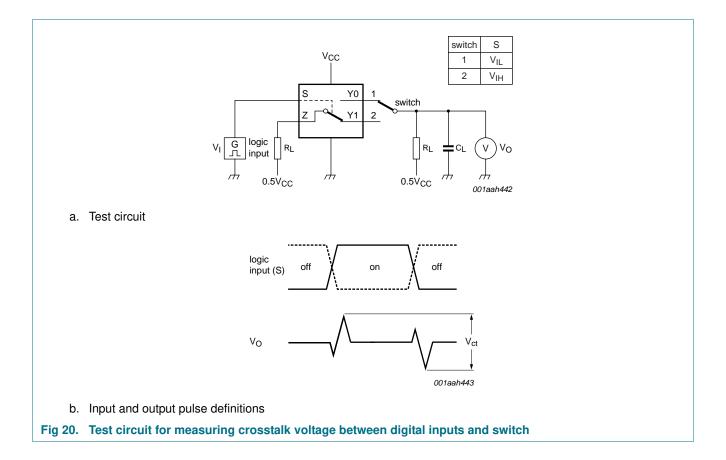
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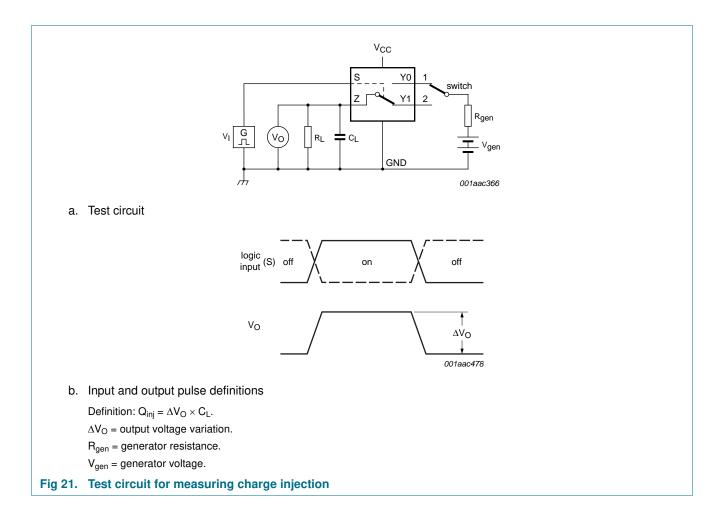




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## 13. Package outline

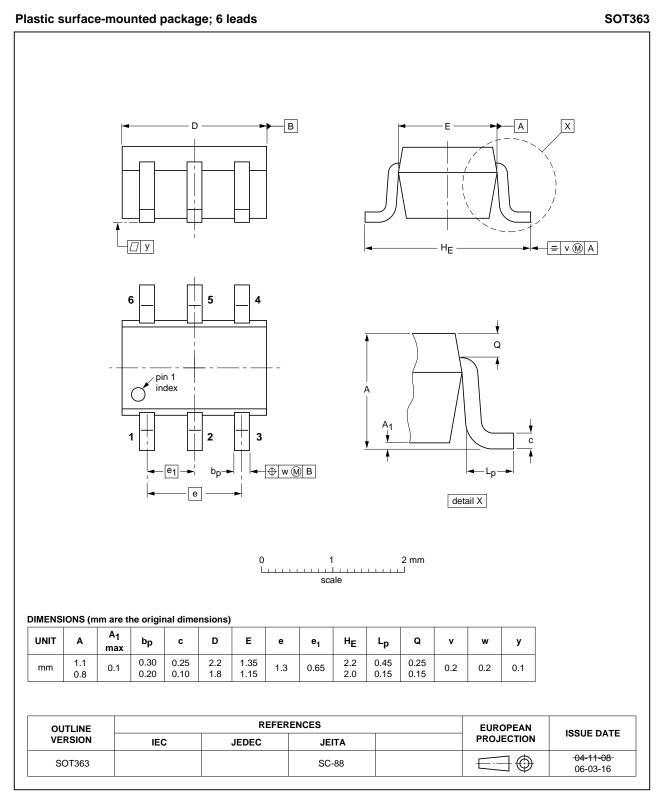


Fig 22. Package outline SOT363 (SC-88)

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## 14. Abbreviations

Table 13.	13. Abbreviations		
Acronym	Description		
CDM	Charged Device Model		
CMOS	Complementary Metal-Oxide Semiconductor		
ESD	ElectroStatic Discharge		
HBM	Human Body Model		
MIL	Military		
MM	Machine Model		
PDA	Personal Digital Assistant		
TTL	Transistor-Transistor Logic		

## 15. Revision history

Table 14. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L1G3157_Q100 v.1	20130523	Product data sheet	-	-

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## 16. Legal information

### 16.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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### Low-ohmic single-pole double-throw analog switch

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Low-ohmic single-pole double-throw analog switch

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